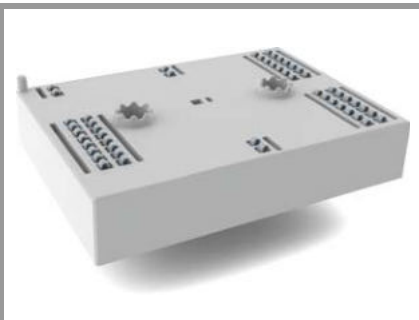




MiniSKiiP® 3 Dual

Half-Bridge

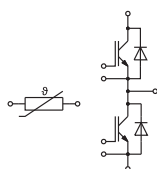
SKiiP 38GB17E4V1

Features*

- Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised: File no. E63532
- NTC T-Sensor

Remarks

- Max. case temperature limited to $T_C=125^\circ\text{C}$
- Product reliability results valid for $T_j \leq 150^\circ\text{C}$ (recommended $T_{j,op} = -40 \dots +150^\circ\text{C}$)

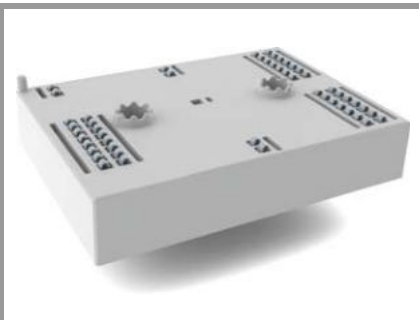


GB

Absolute Maximum Ratings				
Symbol	Conditions		Values	Unit
Inverter - IGBT				
V _{CES}	T _j = 25 °C		1700	V
I _C	T _j = 175 °C	T _s = 25 °C	341	A
		T _s = 70 °C	277	A
I _{Cnom}			300	A
I _{CRM}			900	A
V _{GES}			-20 ... 20	V
t _{psc}	V _{CC} = 1000 V V _{GE} ≤ 15 V V _{CES} ≤ 1700 V	T _j = 150 °C	10	μs
T _j			-40 ... 175	°C
Inverse - Diode				
I _F	T _j = 175 °C	T _s = 25 °C	267	A
		T _s = 70 °C	209	A
I _{FRM}			600	A
I _{FSM}	10 ms, sin 180°, T _j = 150 °C		1566	A
T _j			-40 ... 175	°C
Module				
I _{t(RMS)}	T _{terminal} = 80 °C, 20 A per spring		280	A
T _{stg}	module without TIM		-40 ... 125	°C
V _{isol}	AC sinus 50 Hz, t = 1 min		2500	V

Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
Inverter - IGBT						
V _{CE(sat)}	I _C = 300 A	T _j = 25 °C		1.90	2.20	V
	V _{GE} = 15 V chipelevel	T _j = 150 °C		2.30	2.60	V
V _{CE0}	chipelevel	T _j = 25 °C		0.80	0.90	V
		T _j = 150 °C		0.70	0.80	V
r _{CE}	V _{GE} = 15 V chipelevel	T _j = 25 °C		3.7	4.3	mΩ
		T _j = 150 °C		5.3	6.0	mΩ
V _{GE(th)}	V _{GE} = V _{CE} , I _C = 12 mA		5.2	5.8	6.4	V
I _{CES}	V _{GE} = 0 V	T _j = 25 °C			0.3	mA
	V _{CE} = 1700 V			-		mA
C _{ies}	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz		27.20		nF
C _{oes}		f = 1 MHz		1.06		nF
C _{res}		f = 1 MHz		0.88		nF
Q _G		- 8 V...+ 15 V			2400	
R _{Gint}	T _j = 25 °C			2.1		Ω
t _{d(on)}	V _{CC} = 900 V			216		ns
t _r	I _C = 300 A			52		ns
E _{on}	R _{G on} = 2 Ω			47		mJ
	R _{G off} = 2 Ω					
t _{d(off)}	di/dt _{on} = 7900 A/μs			697		ns
t _f	di/dt _{off} = 2025 A/μs			167		ns
E _{off}	dv/dt = 5084 V/μs V _{GE} = +15/-15 V L _s = 25 nH			102		mJ
R _{th(j-s)}	per IGBT, λ _{paste} =0.8 W/(K*m)			0.15		K/W

SKiiP 38GB17E4V1



MiniSKiiP® 3 Dual

Half-Bridge

SKiiP 38GB17E4V1

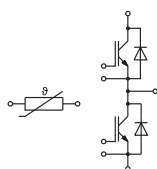
Features*

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Remarks

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Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
Inverse - Diode						
V _F = V _{EC}	I _F = 300 A	T _j = 25 °C		2.00	2.40	V
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.15	2.57	V
V _{F0}	chiplevel	T _j = 25 °C		1.32	1.56	V
		T _j = 150 °C		1.08	1.22	V
r _F	chiplevel	T _j = 25 °C		2.3	2.8	mΩ
		T _j = 150 °C		3.6	4.5	mΩ
I _{RRM}	I _F = 300 A			517		A
Q _{rr}	di/dt _{off} = 8569 A/μs			100		μC
E _{rr}	V _{GE} = -15 V			69		mJ
	V _{CC} = 900 V					
R _{th(j-s)}	per Diode, λ _{paste} =0.8 W/(K*m)			0.24		K/W
Module						
L _{CE}				15		nH
M _s	to heat sink		2		2.5	Nm
w				76		g
Temperature Sensor						
R ₁₀₀	T _c =100°C (R ₂₅ =5 kΩ)			493 ± 5%		Ω
B _{25/85}	R(T)=R ₂₅ *exp[B _{25/85} *(1/T-1/298)], T[K]			3420		K



GB

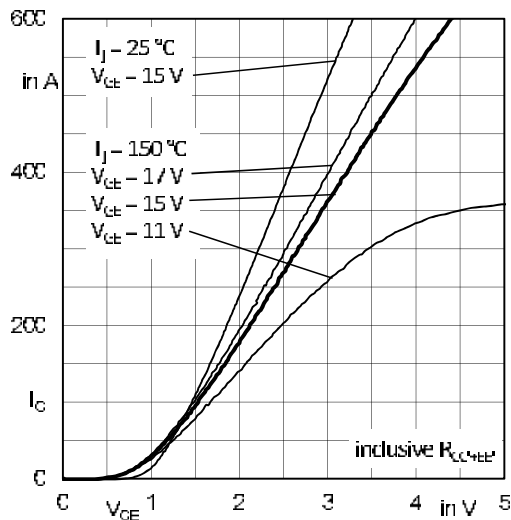


Fig. 1: Typ. output characteristic

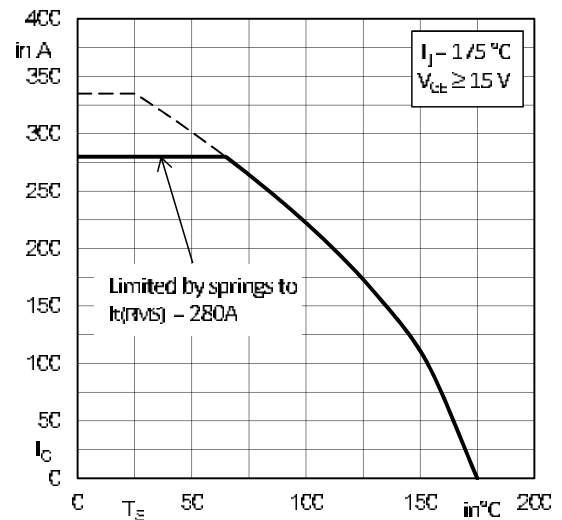


Fig. 2: Rated current vs. temperature $I_C = f(T_S)$

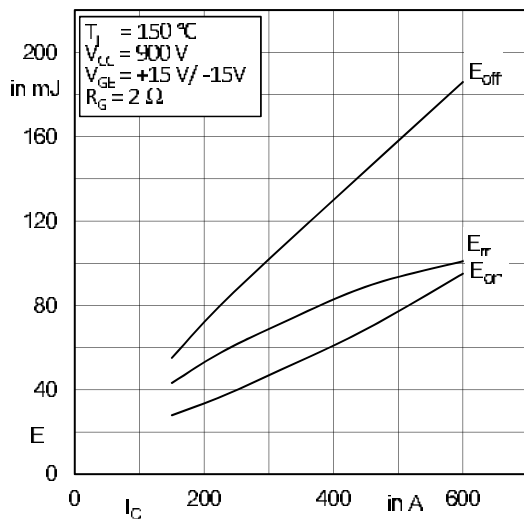


Fig. 3: Typ. turn-on /-off energy = $f(I_C)$

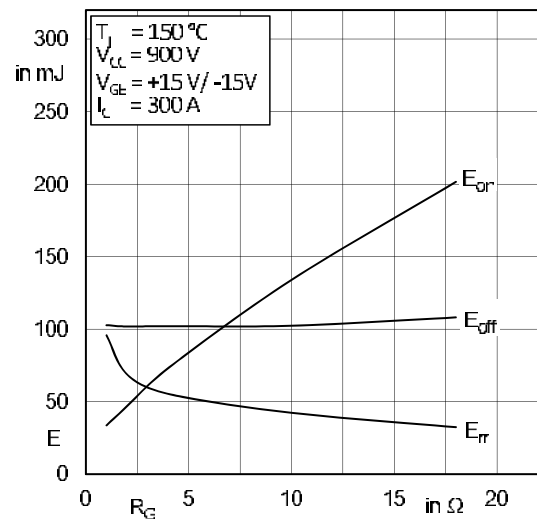


Fig. 4: Typ. turn-on /-off energy = $f(R_G)$

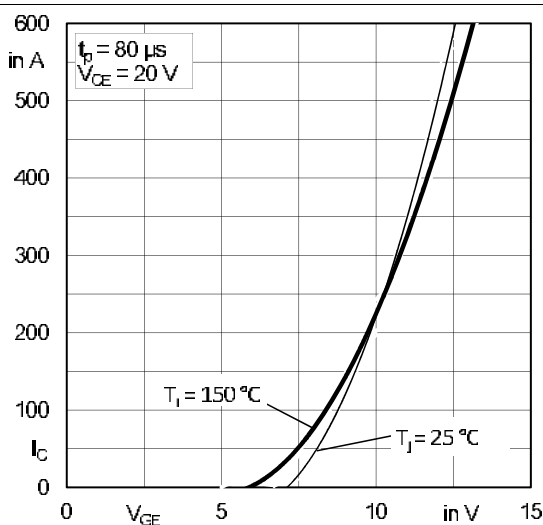


Fig. 5: Typ. transfer characteristic

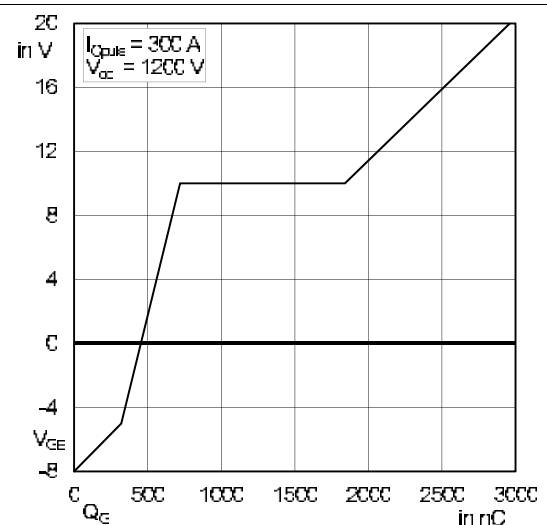
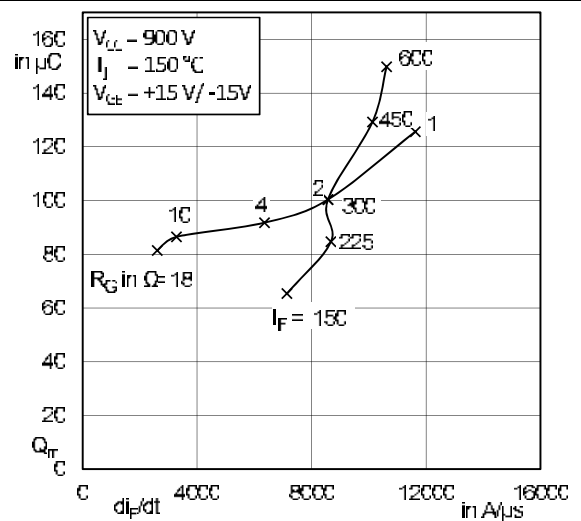
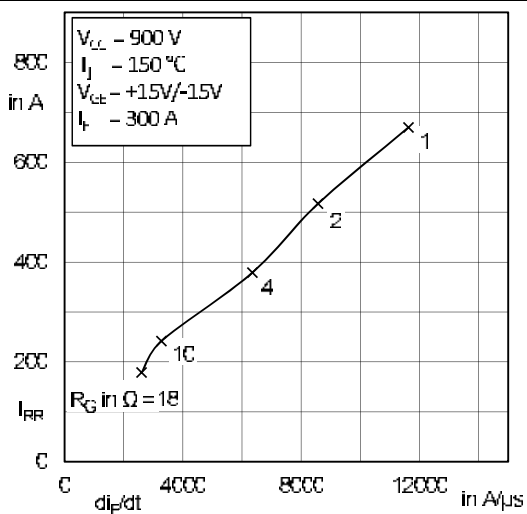
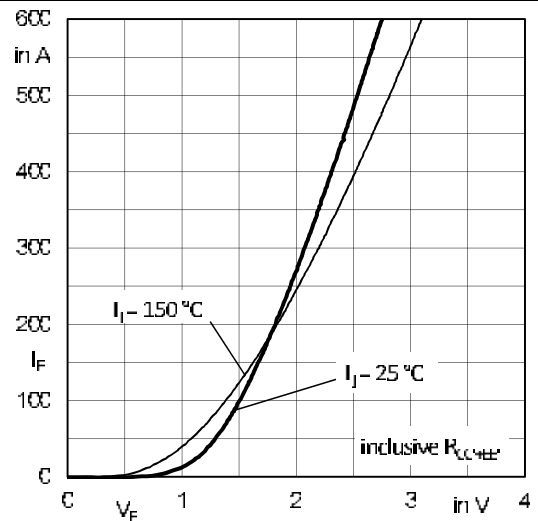
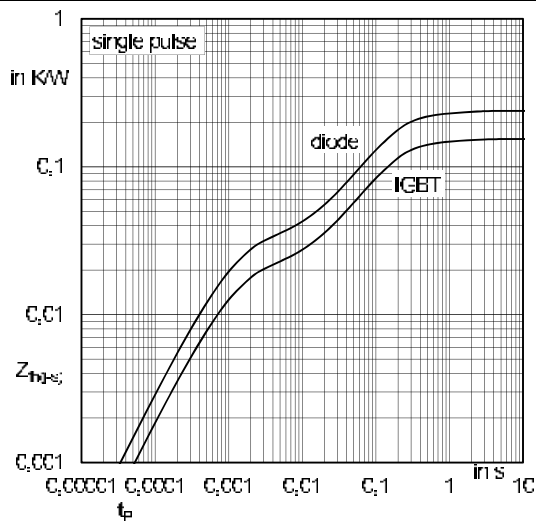
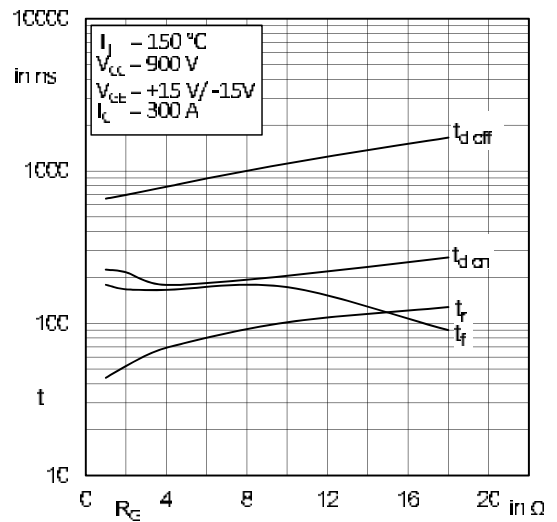
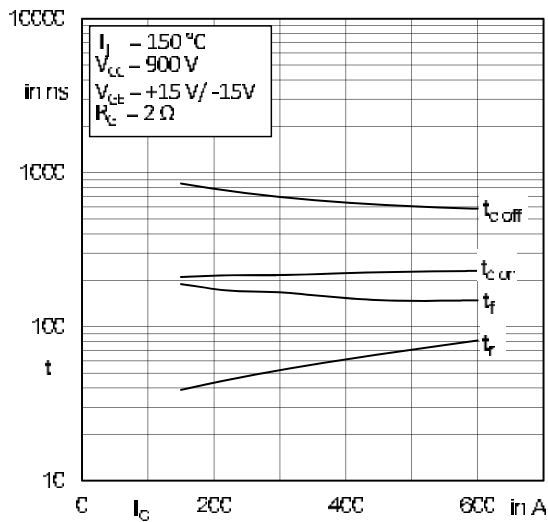


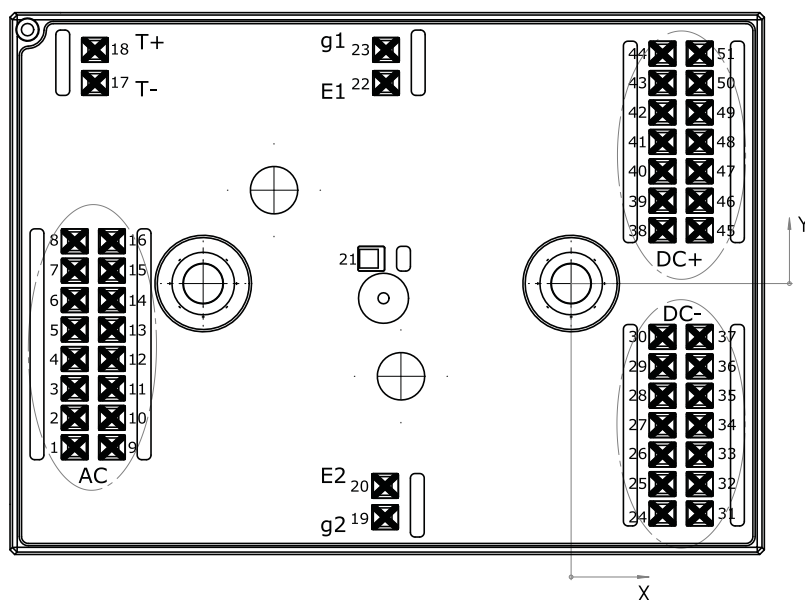
Fig. 6: Typ. gate charge characteristic



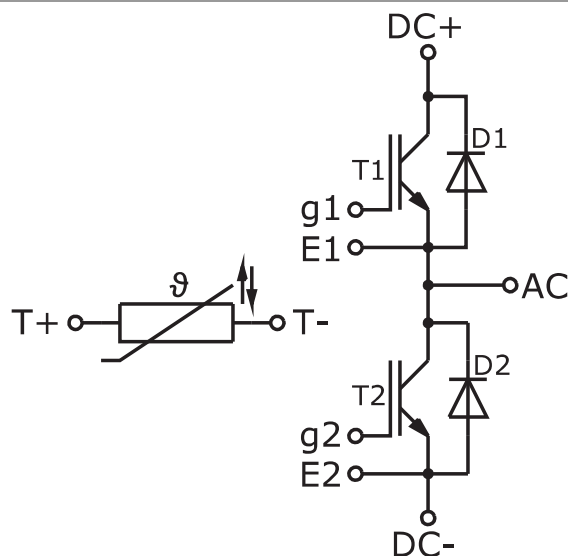
SKiiP 38GB17E4V1

Pin out											
Pin	X	Y	Function	Pin	X	Y	Function	Pin	X	Y	Function
1	-53,98	-17,80	AC	18	-51,78	25,40	T+	35	13,98	-12,20	DC-
2	-53,98	-14,60	AC	19	-20,23	-25,40	g2	36	13,98	-9,00	DC-
3	-53,98	-11,40	AC	20	-20,23	-22,00	E2	37	13,98	-5,80	DC-
4	-53,98	-8,20	AC	21	-21,73	2,70		38	9,93	5,80	DC+
5	-53,98	-5,00	AC	22	-20,13	21,80	E1	39	9,93	9,00	DC+
6	-53,98	-1,80	AC	23	-20,13	25,40	g1	40	9,93	12,20	DC+
7	-53,98	1,40	AC	24	9,93	-25,00	DC-	41	9,93	15,40	DC+
8	-53,98	4,60	AC	25	9,93	-21,80	DC-	42	9,93	18,60	DC+
9	-49,93	-17,80	AC	26	9,93	-18,60	DC-	43	9,93	21,80	DC+
10	-49,93	-14,60	AC	27	9,93	-15,40	DC-	44	9,93	25,00	DC+
11	-49,93	-11,40	AC	28	9,93	-12,20	DC-	45	13,98	5,80	DC+
12	-49,93	-8,20	AC	29	9,93	-9,00	DC-	46	13,98	9,00	DC+
13	-49,93	-5,00	AC	30	9,93	-5,80	DC-	47	13,98	12,20	DC+
14	-49,93	-1,80	AC	31	13,98	-25,00	DC-	48	13,98	15,40	DC+
15	-49,93	1,40	AC	32	13,98	-21,80	DC-	49	13,98	18,60	DC+
16	-49,93	4,60	AC	33	13,98	-18,60	DC-	50	13,98	21,80	DC+
17	-51,78	21,80	T-	34	13,98	-15,40	DC-	51	13,98	25,00	DC+

all values in [mm]



Pinout and Dimensions



Pinout

This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

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